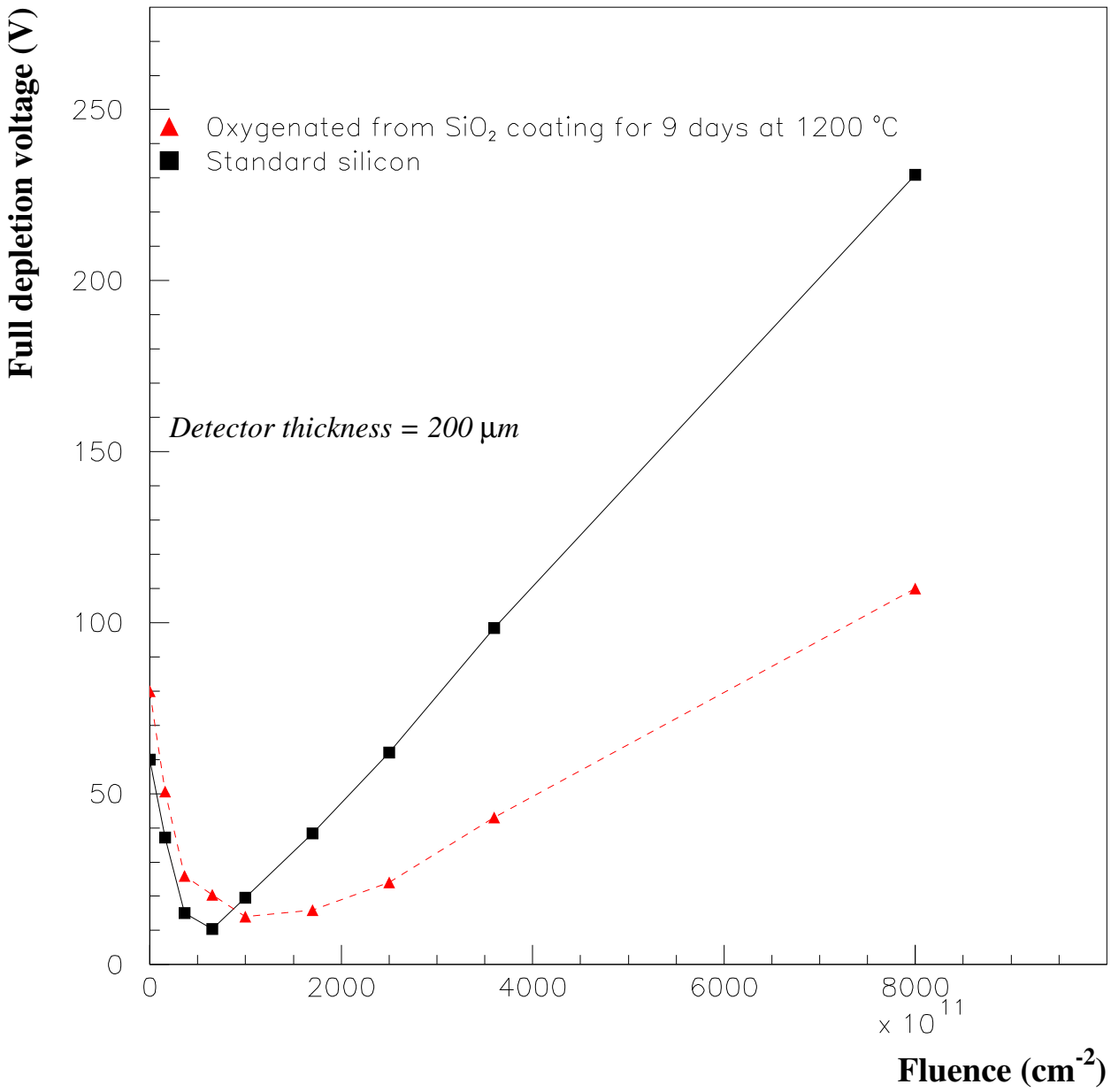Full depletion voltage vs fluence for oxygenated and non-oxygenated silicon detectors